

### GaAs MMIC 6-bit Digital Attenuator Chip, 0.2-20GHz

#### Performance characteristics

Frequency range: 0.2-20GHz Fully positive, integrated logic Insertion loss: 2.8dB@20GHz Attenuation range: 0.5~31.5dB

Bit Count: 6 digits

Attenuation accuracy (RMS): 0.4dB

500hm input/output

Chip size: 1.50 x 1.0 x 0.1mm

#### **Product Introduction**

GDA-0020-6D-P-PD is a GaAs MMIC 6-bit Digital Attenuator Chip, with a frequency range of 0.2-20GHz, insertion loss of 2.0dB, switching speed of 30ns, and integrated driver inside the chip. It adopts+5V power supply and 0/+5V control (compatible with+3.3V).

Usage restriction parameter			
Power supply voltage range	+6V		
Control voltage range	-0.5V~+5.5V		
Maximum input power	+27dBm		
working temperature	-55 ~ +85°C		
Storage temperature	-65 ~ +150°C		

Electrical parameters(Ta=+25°C, VEE=+5V, 0/+5V Control)						
Index	Minimum value	Typical value	Maximum value	Unit		
Frequency range		GHz				
Insertion loss	-	-	dB			
Attenuation range		dB				
Attenuation step		dB				
Attenuation number		bite				
Attenuation accuracy (all frequency bands)	-	-0.6 ~ +1.6	-	dB		
Attenuation accuracy RMS	-	0.4	-	dB		
Additional phase shift	al phase shift -		-	degree		
Input return loss	-	20	-	dB		
Output Return Loss	-	20	-	dB		
Switching speed	-	30	-	ns		
P-1dB@0.2-3GHz @Ground state	-	21	-	dBm		
P-1dB@3-18GHz @Ground	-	25	-	dBm		

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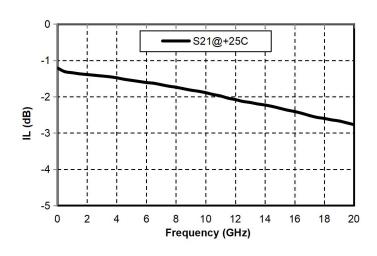


state				
Supply voltage	-	+5	-	V
Power supply current	-	8		mA
Control high level	+2.7	+3.3	+5	V
Control low level	0	-	0.8	V

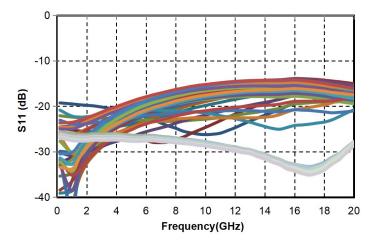
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### Main indicator testing curve

### Insertion loss vs. Frequency

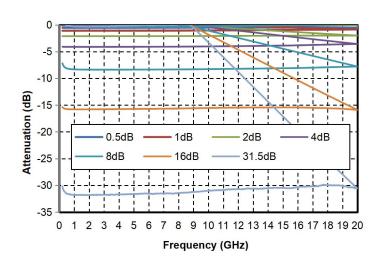


Input echo vs. Frequency

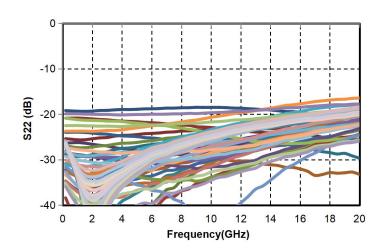


Attenuation accuracy vs. Frequency

### Reference attenuation state vs. Frequency

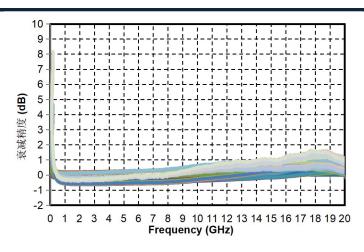


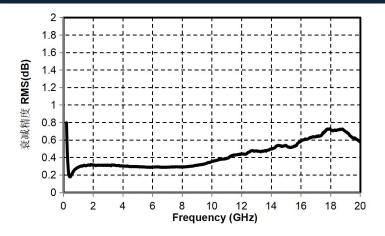
Output echo vs. Frequency



Attenuation accuracy RMS vs. Frequency

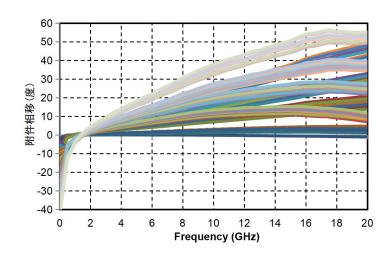




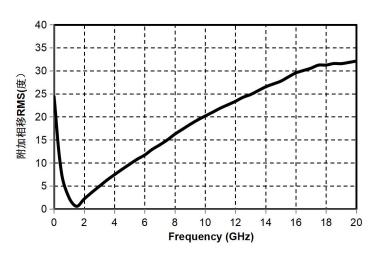


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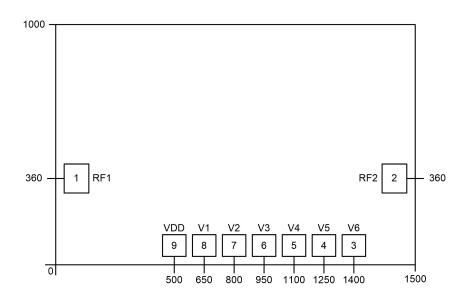
### Additional phase shift vs. Frequency



### Additional phase shift RMS vs.Frequency



#### External structure<sup>2</sup>



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[2] The units in the figure are all micrometers. (Boundary dimension tolerance:  $\pm 50$ um.)

Definition of bonding pressure point				
Bond point number	Functional	Function Description		
	symbols			
1	RF1	The signal input terminal is externally connected to a 50 ohm circuit		
I		and requires an additional broadband DC isolation capacitor		
5	RF2	The signal output terminal is externally connected to a 50 ohm circu		
		and requires an additional broadband DC isolation capacitor		
9	VDD	The chip power port requires an external 100pF capacitor		
3~8	VC	Control pads, attenuation control see truth table		
Chip bottom	GND	The bottom of the chip needs to have sufficient and good contact		
		with RF and DC ground		

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Truth table							
VDD	V1	V2	V3	V4	V5	V6	Attenuation amount
	0	0	0	0	0	0	Initial state N=0; The
							attenuation amount is 0
	1	0	0	0	0	0	Initial state N=1; The
							attenuation amount is 0.5
	0	1	0	0	0	0	Initial state N=2; Attenuation
							of 1
	0	0	1	0	0	0	Initial state N=4; Attenuation
+5V							of 2
+3 <i>V</i>	0	0	0	1	0	0	Initial state N=8; The
							attenuation amount is 4
	0	0	0	0	1	0	Initial state N=16; The
							attenuation amount is 8
	0	0	0	0	0	1	Initial state N=32; The
							attenuation amount is 16
	1	1	1	1	1	1	Initial state N=63; The
							attenuation amount is 31.5

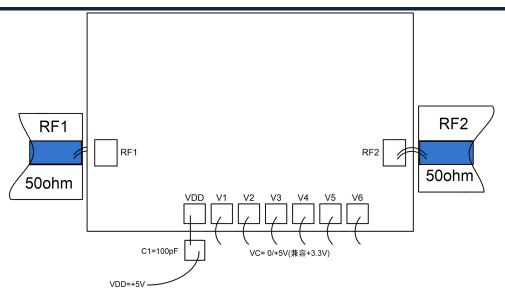
High (1),  $+2.7 \sim +5V$ ; Low (0),  $0 \sim +0.8V$ 

Suggested assembly diagram

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#### Precautions for use

- The chip needs to be stored in a container with anti-static function and stored in a nitrogen environment.
- Attempting to clean the surface of bare chips using wet chemical methods is prohibited.
- Please strictly comply with ESD protection requirements to avoid static damage to bare chips.
- Routine operation: Please use precision pointed tweezers to remove the bare chip. During the operation, avoid tools or fingers touching the surface of the chip.
- Suggestion for mounting operation: Bare chip installation can use AuSn solder eutectic sintering or conductive adhesive bonding process. The installation surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold tin ratio of 80/20. The working surface temperature reached 255 °C, and the tool (vacuum chuck) temperature reached 265 °C. When a high-temperature mixed gas (nitrogen to hydrogen ratio of 90/10) is blown onto the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip stay above 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive adhesive applied should be as small as possible. After placing
  the chip in the installation position, the conductive adhesive can be vaguely visible around it. Please follow
  the information provided by the conductive adhesive manufacturer for curing conditions.
- Suggestion for bonding operation: Both spherical or wedge-shaped bonding should be used Φ 0.025mm (1mil) gold wire. Thermal ultrasonic bonding temperature is 150 °C. The pressure of the spherical bonding cutter is 40-50GF, and the pressure of the wedge bonding cutter is 18-22GF. Use as little ultrasonic energy as possible. The bonding process starts at the pressing point on the chip and ends at the packaging (or substrate).

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